# COMPLEMENTARY SILICON TRANSISTORS

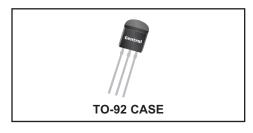


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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N5172 and 2N6076 are complementary silicon small signal transistors designed for general purpose applications.





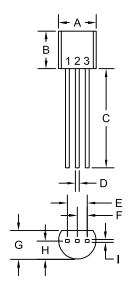
MAXIMUM RATINGS: (TA=25°C)	SYMBOL		UNITS
Collector-Base Voltage	$V_{CBO}$	25	V
Collector-Emitter Voltage	$V_{CEO}$	25	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Continuous Collector Current	I <sub>C</sub>	100	mA
Power Dissipation	$P_{D}$	625	mW
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stq</sub>	-65 to +150	°C

ELECTRICAL	CHARACTERISTICS: (T <sub>A</sub> =25°C	unless otherwise	noted)		
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
ICBO	V <sub>CB</sub> =25V			100	nA
ICBO	V <sub>CB</sub> =25V, T <sub>A</sub> =100°C			10	μΑ
I <sub>CES</sub>	V <sub>CE</sub> =25V			100	nA
I <sub>EBO</sub>	V <sub>EB</sub> =5.0V (2N5172)			100	nA
I <sub>EBO</sub>	V <sub>EB</sub> =3.0V (2N6076)			100	nA
BV <sub>CEO</sub>	I <sub>C</sub> =10mA	25			V
V <sub>CE</sub> (SAT)	I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA			0.25	V
V <sub>BE</sub> (SAT)	I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA			0.80	V
V <sub>BE(ON)</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	0.5		1.2	V
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	100		500	
h <sub>fe</sub>	$V_{CE}$ =10V, $I_{C}$ =10mA, f=1.0kHz	100		750	
$f_T$	V <sub>CB</sub> =5.0V, I <sub>C</sub> =2.0mA		200		MHz
$C_{ob}$	$V_{CB}$ =10V, $I_E$ =0, f=1.0MHz	1.0		13	pF

# COMPLEMENTARY **SILICON TRANSISTORS**



## **TO-92 CASE - MECHANICAL OUTLINE**



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
A (DIA)	0.175	0.205	4.45	5.21		
В	0.170	0.210	4.32	5.33		
С	0.500	-	12.70	-		
D	0.016	0.022	0.41	0.56		
E	0.100		2.54			
F	0.050		1.27			
G	0.125	0.165	3.18	4.19		
Н	0.080	0.105	2.03	2.67		
	0.015		0.38			

TO-92 (REV: R1)

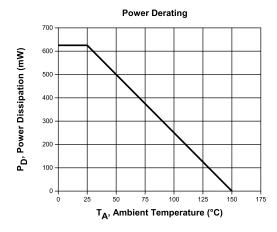
# LEAD CODE:

- Emitter
  Collector
- 3) Base

R1

## MARKING:

**FULL PART NUMBER** 

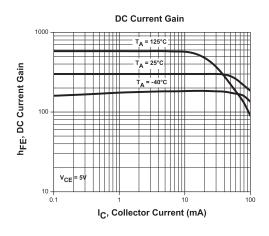


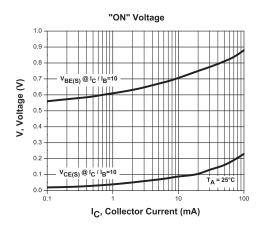
R1 (7-February 2014)

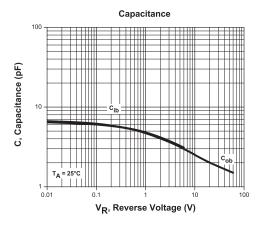


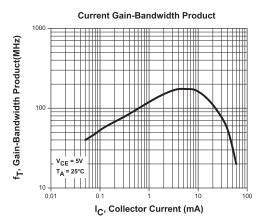


## NPN TYPICAL ELECTRICAL CHARACTERISTICS





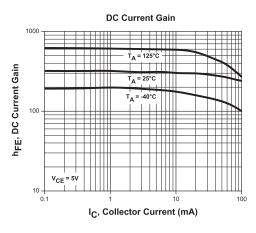


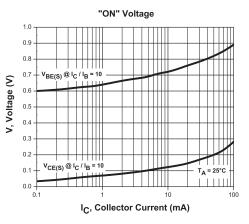


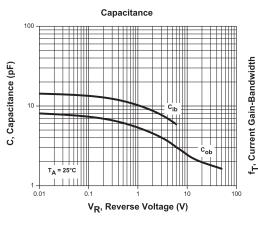


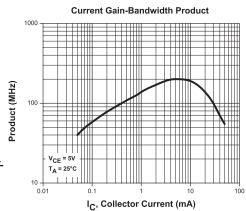


#### PNP TYPICAL ELECTRICAL CHARACTERISTICS









#### **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

#### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### **CONTACT US**

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